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# Stable green and red dual-color emission in all-inorganic halide-mixed perovskite single microsheets†

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Recently, all-inorganic perovskites have attracted tremendous attention due to their excellent optoelectronic properties and extensive potential applications. However, these perovskites usually show a single emission wavelength because of the high ionic migration. Herein, we synthesized all-inorganic halide-mixed perovskite  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheets with high crystal quality using the anti-solvent solution method and observed extraordinary green and red dual-color emission in single  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheets. Power dependent PL spectra reveal excitonic and defect related recombination features of  $\text{CsPbBr}_3$  and  $\text{CsPbI}_3$  for the green and red emission. Temperature dependent PL spectra indicated a distinctive exciton–phonon coupling strength in  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheets compared with pure  $\text{CsPbBr}_3$  and  $\text{CsPbI}_3$ . The PL dynamics showing longer emission lifetime further confirmed this conclusion. Our work not only provides a novel strategy to produce stable dual-color emission integration, but also promotes the fundamental insight into the emission dynamics and exciton/free carrier related photophysics in all-inorganic halide-mixed perovskites.

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## 1 Introduction

In the last decade, lead halide perovskites have attracted a great deal of attention due to their excellent properties including long charge carrier diffusion length, high absorption coefficient, remarkable PL quantum yield, high defect tolerance and tunable bandgap over the entire visible spectral region.<sup>1–6</sup> Benefiting from these merits, lead halide perovskites have been expected to be promising building blocks for high-performance electronic and optoelectronic devices.<sup>4,7–11</sup> At present most of these perovskites show single-color emission.<sup>1,2,9,10,12</sup> However, dual-colors or multi-colors integrated emission in a single perovskite is desired due to its significant application in a wide range such as white emission, color display, integrated optics etc.

Three pathways have been applied to realize the dual-colors emission in cesium lead halide perovskites. Firstly, impurity

doping is the straightforward method to endow semiconductor with novel optical and electronic functionalities. It have been reported that lead-halide perovskite nanocrystals exhibited the band-edge and dopant Mn ions emission simultaneously.<sup>13–15</sup> The dual-colors emission intensity could be tuned by the dopant concentration. Secondly, addition of surface ligands also could introduce a new emission peak due to the interaction between the surface ligands and the host lattice. By adjusting the content of ligands on surface, the intensity of the emission peaks can be regulated effectively.<sup>16</sup> Lastly, the spatially resolved  $\text{CsPbX}_3$  nanowire hetero-junctions can exhibit evident dual-colors or multicolors emission.<sup>6,13–20</sup> Although achieving much harvest, these approaches to realize the dual-colors emission still have some shortcomings. For example,  $\text{Mn}^{2+}$  doping is nerveless for  $\text{CsPbBr}_3$  and  $\text{CsPbI}_3$ . The surface ligands are restricted to the nanometer scale crystals while the heterogeneous structures suffered from the complex implementation.<sup>6,13–20</sup> Therefore, hunting for efficient approach to realize the dual-colors emission in cesium lead halide perovskites is needed. Very recently, light-induced phase segregation is prevalent for organic–inorganic and all-inorganic halide-mixed perovskites. Under light irradiation, the halide-mixed perovskites degenerated into multi-domains with diverse composition and band gap due to the net migration of ions through halogen vacancies,<sup>21–29</sup> yielding two or multi- PL peaks integration. Unfortunately, this phenomenon is unstable and the domains will recover to the original uniform phase quickly after turn off the light illumination.<sup>27–30</sup>

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In this work, we exhibit the stable green and red dual-colors emission from a simple anti-solvent solution method synthesized  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheet. Power and temperature dependent PL spectra were performed to reveal the green and red emission origin from the excitonic and defect related recombination of  $\text{CsPbBr}_3$  and  $\text{CsPbI}_3$ , respectively. Further analysis of FWHM and peak intensity extracted from the temperature-dependent PL revealed the distinctive exciton-phonon coupling strength of two emission bands. Lattice stress induced by the I-rich domains may play an important contribution to this distinct change. These results not only provide a novel strategy to satisfy the need of multi-colors emission integration, but also promote the fundamental insight into the emission dynamics and exciton/free carriers related photophysics in all-inorganic halide-mixed perovskites.

## 2 Experimental section

### 2.1 Chemical reagents

All the chemicals and reagents, CsBr (99.5%, Aladdin), CsI (99.9%, Aladdin),  $\text{PbBr}_2$  (99.0%, Aladdin), dimethyl sulfoxide (DMSO, 99.9%, Macklin), *N,N*-dimethylformamide (DMF, 99.9%, Macklin), isopropanol (99.9%, Macklin), were used as received without any further purification.

### 2.2 Synthesis procedures

Firstly, 0.1 mmol CsI and 0.2 mmol  $\text{PbBr}_2$  powder were dissolved into 4 mL of DMF. 0.1 mmol CsBr was dissolved into 2 mL of DMSO. Then, the CsI- $\text{PbBr}_2$  and CsBr solution were mixed together. Finally, 50  $\mu\text{L}$  of the as-prepared mixed solution was dripped on a silicon slice, which was placed next to a glass dish containing 9 mL isopropanol. Another glass dish with diameter of 10.5 cm was placed upside down to cover the silicon slice and the glass dish. The schematic diagram was shown in Fig. S1a.† The whole equipment was kept at 60 °C until all the solvent evaporated up. After tens of minutes, yellowish-brown precipitation can be observed by naked eye. The precipitated  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheets were directly used for further characterization. Additional 5  $\mu\text{L}$   $\gamma$ -butyrolactone or 1,2-propylene carbonate was helpful for optimize the product. It is needed to note that all these processes were performed under atmospheric environment in the ultra-clean chamber.

### 2.3 Structure and optical characterizations

Optical microscopy (Olympus BX53, integrated into the Raman spectrometer) and scanning electron microscopy (SEM, FEI Nova nanoSEM-450) were used to characterize the size and morphology of as-synthesized product. The chemical composition analysis was carried out using the energy-dispersive spectrometry (EDS, Oxford X-max 20, attached on the SEM). Powder X-ray diffraction (PXRD) measurement was performed at room temperature by Bruker D8 Discover diffractometer to determine the crystallographic phase structure. The steady-state PL spectra of individual microsheet were obtained using a high-resolution Raman spectrometer (LabRAM HR Evolution, Horiba JY) with 532 and 355 nm continuous wave (CW) lasers as excitation light

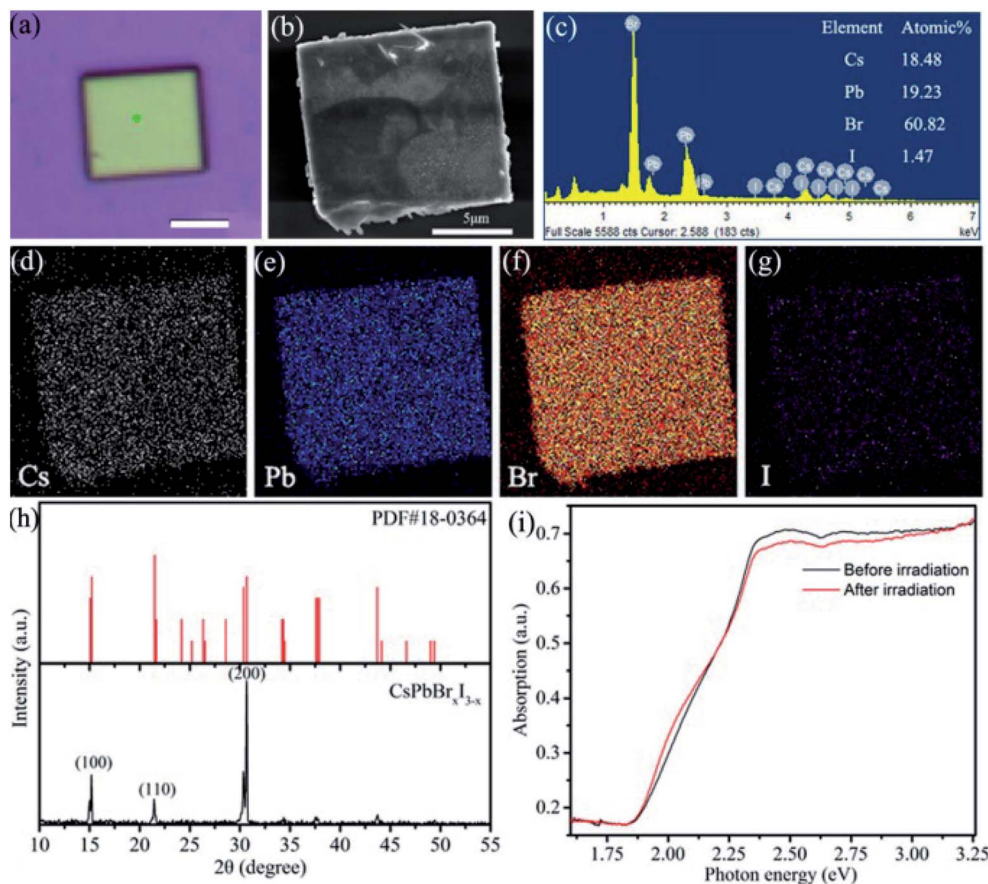
sources. Here, the laser power is 0.2 mW and numerical aperture (NA) of the object is 0.8. The diameter of light spot equals to 1.22  $\lambda/\text{NA}$ . The back scattered PL was collected. Liquid nitrogen cryogenic platform (Linkam THMS 600) was used for the temperature-dependent measurement. The time-resolved PL (TRPL) was collected by the time-correlated single-photon counting (TCSPC) system (PicoQuant GmbH, PicoHarp 300) with a picosecond pulsed laser diode (Picoquant PDL 800-B,  $\lambda = 375$  nm, 10–80 MHz) as the excitation source.

## 3 Results and discussion

The  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheets were synthesized by a simple anti-solvent solution method (as shown in Fig. S1a†). Here, isopropanol was chosen as the anti-solvent because it can form a neat morphology and would not damage apparently the optoelectronic performance of halide perovskites. As shown in Fig. S1b,† a large amount of  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheets with yellowish-brown color have been obtained. The optical and SEM images in Fig. 1a and b confirmed the rectangular sheet-like morphology with a uniform yellowish-brown color and smooth surface. The width and length are tens of micrometers. Fig. S1c and d† showed the morphology of other samples. The chemical composition of as-synthesized micro-sheets was characterized by EDS. The micro-sheet was constituted by Cs, Pb, and halides (Br and I) with a ratio nearly to 1 : 1 : 3 (Fig. 1c), although the proportion of iodine is only 1.47%. EDS mapping was further performed to investigate the element distribution. Fig. 1d–g showed the uniform distribution of Cs, Pb, Br and I. PXRD was used to determine the crystal structure. These observed diffraction peaks correspond to the (200), (110), (100) lattice planes of monoclinic phase  $\text{CsPbBr}_x\text{I}_{3-x}$ .<sup>31–33</sup> The high intensity of (200) might indicate the preferential growth direction. The absence of diffraction peaks of  $\text{PbBr}_2$ , CsBr,  $\text{CsPbI}_3$ , and  $\text{Cs}_4\text{PbBr}_6$  demonstrates the high purity and high crystalline of the as-synthesized  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheets.<sup>33–35</sup> It is noted that the minor iodine has little effect on the crystal structure. However, the inclusion of this minor iodine has important effect on the optical properties. The absorption spectrum of  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheets shows an additional low-energy shoulder extending to 665 nm ( $\sim 1.85$  eV) compared to  $\text{CsPbBr}_3$ ,<sup>32,36</sup> demonstrating the remarkable variation of electronic band structure with even little iodine addition (the black curve in Fig. 1i). After consecutive irradiation ( $\lambda = 445$  nm) for 90 min, the absorption spectrum shows a negligible change (the red curve in Fig. 1i), indicating that the irradiation did not induce large change in crystal structure or phase composition. Both the slight loss of green region and increase of the low-energy shoulder band show a signature of phase segregation, which is prevalent in organic–inorganic halide-mixed perovskites.<sup>21,26,37,38</sup>

Fig. 2a is the evolution of PL spectra with illumination time for a single  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheet, showing the dual-colors emission. The peak shift of high energy (2.3–2.4 eV) is negligible while its intensity reduces a little. Meantime, the low energy peak redshifts continually from  $\sim 1.88$  eV to  $\sim 1.78$  eV with increased intensity. It's reported that the cubic bulk  $\text{CsPbI}_3$

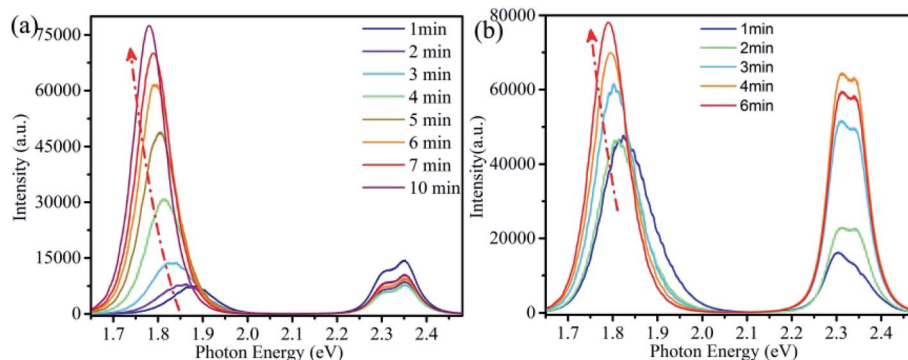




**Fig. 1** (a–c) Optical image, SEM and EDS of a single CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheet. Scale bar in (a) is 5 μm. (d–g) EDS mappings of element Cs, Pb, Br and I. (h) PXRD patterns of CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheets. (i) Absorption spectra of CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheets before and after the light irradiation ( $\lambda = 445$  nm).

has a band gap of  $\sim 1.8$  eV (691 nm).<sup>9,32,39–41</sup> Comparison with the PL of bulk CsPbI<sub>3</sub> crystals, the present PL band shows a blue shift and there are several reasons contribution to this blue shift. First, quantum dots with small size usually cause the PL blue shift due to the quantum confinement effect. This is reasonable in the present case because the little content of iodine will yield the quantum dots-like structures under laser

illumination, forming the compound of CsPbI<sub>3</sub> QDs embedded into CsPbBr<sub>3</sub> matrix. Secondly, a little bromine might doping into the CsPbI<sub>3</sub> lattice to form CsPbI<sub>3-x</sub>Br<sub>x</sub> alloy, yielding the PL blue shift due to the larger band gap of CsPbBr<sub>3</sub>. The significant redshift and enhanced intensity of the low energy peak confirm the occurrence of light induced phase segregation, as demonstrated in the absorption spectra. Similar redshift of PL spectra



**Fig. 2** (a) PL spectra evolution of a single CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheet with the irradiation time of CW laser (wavelength  $\lambda = 355$  nm and power  $P = 0.2$  mW). (b) PL spectra of the same CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheet after stored in desiccator for 72 h.



were prevalent in the halide-mixed counterparts.<sup>21–23,27,28,30,42–44</sup> As revealed in previous studies that light irradiation induced local electric field or gradient carrier concentration, halide ions would migrate through the assistance of defects.<sup>22–27,42–46</sup> For halide-mixed perovskites, migration of halide ions would form the phase segregation process due to the different activation energy of halide ions, yielding the segmented perovskites with diverse halide compositions and bandgaps.<sup>21–23,25,26,28–30,42,43,45</sup> Therefore, PL peak shifts with varied intensity under light irradiation. In the present CsPbBr<sub>x</sub>I<sub>3–x</sub> micro-sheets, laser irradiation induced phase segregation give rise to the formation of local iodine-rich and bromine-rich domains, leading to the peak shifts and intensity variation of the two corresponding peaks. For convenience of the following discussion, we note the high and low energy peaks as Br-rich peak and I-rich peak, respectively. In the previous papers, the CsPbBr<sub>2</sub>I thin film showed a continuous red shifted peak position of the observed single PL band while the CsPbBr<sub>x</sub>I<sub>3–x</sub> micro-platelet demonstrated an intensity variation oppositely of the observed two peaks under laser excitation.<sup>42,45</sup> For our CsPbBr<sub>x</sub>I<sub>3–x</sub> micro-sheets, the peak position shifts of the observed two peaks are not evident and the intensities of both peaks increase simultaneously, demonstrating the better stability of the green and red dual-emissions. Under laser irradiation, due to the laser irradiation induced phase segregation effect, the content and size of iodine-rich domains evolve into CsPbI<sub>3</sub> with the illumination time, yielding the more evident shift of the low energy peak. While for the high energy peak, the phase segregation process almost has no effect on the content and size of CsPbBr<sub>3</sub> lattice host, endowing the little shift of high energy peak with the illumination time.<sup>42,45</sup>

In addition to phase segregation, light irradiation can also induce defect healing effect, resulting in the increase of both PL intensity and lifetime.<sup>24,47–50</sup> To gain further insight into the time-dependent PL spectra, we performed Lorentz decomposition for Br-rich peaks while Gaussian decomposition for I-rich peaks. As shown in Fig. S2a,† the Br-rich peak decomposed into two adjacent peaks at 2.353 and 2.302 eV with full width at half maximum (FWHM) of 64 and 59 meV. The two peaks varied in a synchronous way that their peak energy and FWHM decreased monotonically while the peak intensity weakened first and then increased gradually. The I-rich peak also decomposed into two adjacent peaks (Fig. S2b†). These two adjacent peaks firstly centered at 1.881 and 1.873 eV with FWHM of 87.42 and 138.49 meV. Subsequently, under continuous laser irradiation, the two peaks gradually shifted to low energy position with different rate. Their FWHM decreased and intensity increased in inhomogeneous ways. Finally, the two peaks fixed at 1.779 and 1.785 eV and their FWHM decreased to 66.65 and 119 meV.

Generally, FWHM could be affected by crystal size, carrier-phonon interaction or the defect-related inhomogeneous broadening.<sup>15,32,51–53</sup> For the as-synthesized CsPbBr<sub>x</sub>I<sub>3–x</sub> micro-sheets, the decrease of FWHM could be induced by either phase segregation induced size increases of I-rich domains or defect healing effect caused restore of defects. It is worth to note that Lorentz decomposition was suitable for the fitting of Br-

rich peak while Gaussian decomposition was used for I-rich peak fitting. Gaussian decomposition does not yield a good fit to Br-rich peak when just consider two peaks. The case is similar for Lorentz decomposition in I-rich peak. Therefore, this result suggests that the defects or impurities related recombination of I-rich peak and also approves the happen of laser induced defect healing.

More interesting, as a significant difference from lots of the previous reports, which demonstrated that segregated segmentations would recover quickly to the uniform alloy phase after stored in dark for tens of minutes,<sup>27–30,54</sup> the present I-rich peak does not completely recover to the initial position shown in Fig. 2a after stored in desiccator for 3 days, as shown in Fig. 2b. Meanwhile, the PL spectra recover to a similar profile after laser irradiation, indicating the high stability of the dual-colors emission from CsPbBr<sub>x</sub>I<sub>3–x</sub> microsheets.

Another interesting observation is that both Br-rich peak and I-rich peak are composed by two adjacent peaks. This observed phenomenon is not an occasional case,<sup>32,40,55–57</sup> and its origin is still in dispute. To have a look into the nature of the four constitutive peaks, we performed the laser power-dependent PL. It is well known that the near-band-edge luminescence intensity  $I_{\text{PL}}$  is proportional to the laser power  $P$  ( $I_{\text{PL}} \propto P^\alpha$ ). Generally, the coefficient  $\alpha$  is  $1 < \alpha < 2$  for free- and bound-exciton emission while less than 1 for donor-acceptor pair recombination.<sup>9,31,58</sup> We collected the PL spectra under the excitation of 355 nm CW laser with a series of power between 0.002–0.2 mW at the same position. The comparison of PL spectra excited by high and low excitation power is shown in Fig. S3a and b.† The lower excitation power yields smaller influence on CsPbBr<sub>x</sub>I<sub>3–x</sub> micro-sheets. That is, laser induced defect healing has tiny influence on PL intensity. We carried out this strategy after completion of phase segregation to avoid its influence as much as possible. The I-rich peak fixed at  $\sim 1.78$  eV. Fig. 3a is the power-dependent PL spectra and Fig. 3b and c are the corresponding fitted curves of PL intensity *versus* excitation power. The coefficient  $\alpha$  are determined to be 1.29 and 1.205 for the two Br-rich peaks whereas 1.06 and 0.95 for the two I-rich peaks. So, two Br-rich peaks derive from excitonic emission.<sup>31,32</sup> But for two I-rich peaks, the coefficient  $\alpha$  was complex. To exclude the possible influence from Br-rich domains to I-rich domains, we collected a series of PL spectra at the same point under excitation of 532 nm laser with power of 0.005 mW, 0.05 mW, 0.5 mW and 1.6 mW (Fig. S4†). The corresponding  $\alpha$  are 0.69 and 0.57, indicating that the two I-rich peaks shall origin from donor-acceptor pair recombination. Fig. S5† is the PL spectra and corresponding fitting curves of another sample, which also support this conclusion. This conclusion is consistent with the behavior of FWHM in Fig. 2a.

For organic-inorganic hybrid halide-mixed perovskites, it's believed that the repetition rate play a more important role on the phase separation than the laser power.<sup>27,28</sup> For the all-inorganic halide-mixed perovskites, such as CsPbBr<sub>x</sub>I<sub>3–x</sub> nanowires, it has been reported that no photoinduced phase segregation was observed under excitation of femtosecond pulsed laser ( $\lambda = 400$  nm, 150 fs, 1 kHz).<sup>17</sup> In this work, we used a picosecond laser diode ( $\lambda = 375$  nm, 10 MHz, 60 ps,  $\sim 200$  pJ





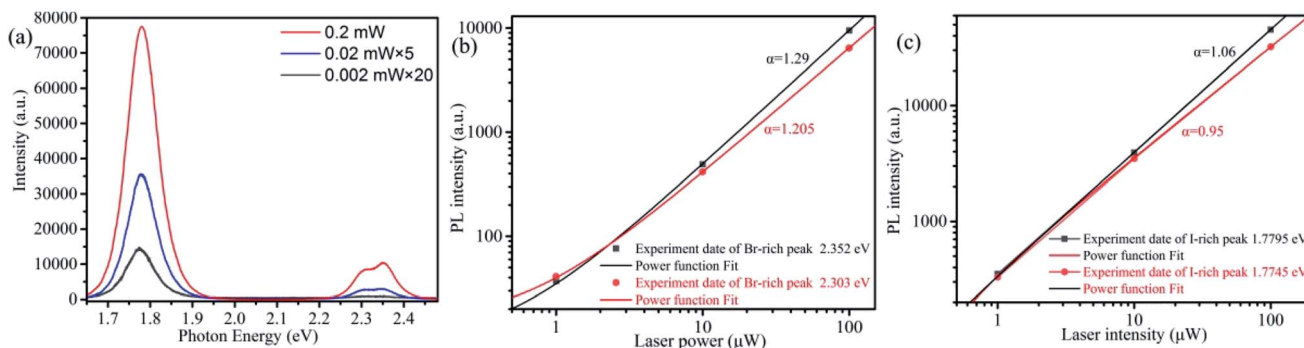


Fig. 3 (a) Power-dependent PL spectra of a single  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheet under the 355 nm CW laser excitation. (b and c) The log-log plot of PL intensity versus laser power for the two Br-rich peaks and I-rich peaks extracted from Fig. 3a (color points). The color solid lines are the fitted curves using power function.

per pulse) to excite the single  $\text{CsPbBr}_x\text{I}_{3-x}$  micro-sheet. The irradiation time dependent PL was shown in Fig. 4a. Obvious red shift of I-rich peaks can be observed. Peak decomposition also revealed that the I-rich peak contained two components with decreased FWHM under increased pulsed laser excitation time (Fig. S6b†). However, the Br-rich peaks contained only one peak (Fig. S6a†), disagreeing with the results of CW laser excitation. The reason may attribute to the different interaction way within the  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheet for pulsed laser and CW laser.<sup>27,28,30</sup> The time-resolved PL of a single  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheet was measured to obtain more information about the photo-excited carrier dynamics, as shown in Fig. 4b and c. These PL decay curves can be fitted with an exponential function:  $I(t) = A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2) + \dots$ , here  $\tau_n$  represents the decay time of two kind of recombination mechanism,  $A_n$  is the amplitudes of  $\tau_n$ .<sup>24,36,49,50,59</sup> These decay results and the corresponding curves have been fitted well, as shown in Tables S1 and S2.† It's distinct that the dominant components continuously increase for both Br-rich ( $\tau_{\text{Br}}^1$  and  $\tau_{\text{Br}}^2$ ) and I-rich ( $\tau_{\text{I}}^1$  and  $\tau_{\text{I}}^2$ ) peak under laser excitation, indicating the decrease of defect under excitation of laser,<sup>24,49,50</sup> consistent with the results of time- and power-dependent PL spectra. It has been proposed that migration of halide ions is defect-mediated.<sup>27,29,54,57</sup> Decreased defect concentration would reduce light induced ion migration. To the negative value of amplitudes  $A_2$ , there was

proposed that it stands for a rise kinetics of PL signal, indicating a continuous population after laser excitation.<sup>59</sup> Negative value of amplitude could be treated as a signature of energy transfer.<sup>59</sup> Due to the bigger bandgap of Br-rich phase than the I-rich phase, re-absorption and carrier transfer from Br-rich phase to I-rich phase is reasonable. In fact, we do observe the stronger emission intensity of I-rich phase than the Br-rich phase despite the minor value of I/Br. In addition, the two lifetime components of Br-rich phase are smaller than the counterparts of  $\text{CsPbBr}_3$  quantum dots.<sup>36,39</sup> Such decreased lifetime was also observed in  $\text{MAPbBr}_3/\text{Ti}_3\text{C}_2\text{T}_x$  due to energy transfer from  $\text{MAPbBr}_3$  to  $\text{Ti}_3\text{C}_2\text{T}_x$ .<sup>59,60</sup> For the all amplitudes, their variation reflect the population change to corresponding recombination mechanism, which could be influenced by either irradiation induced defect healing or ion migration generated defects (vacancies or interstitials).<sup>23,24,42,45,46</sup> As it's believed that with the aid of halogen vacancies, the laser induced electric field or gradient carrier concentration can drive halide anion to migrate and rearrange, yielding the phase segregation into I-rich phases and net  $\text{CsPbBr}_3$  lattice under sufficient long excitation.<sup>23,27,29,42,45</sup> This evolution could be interpreted as the arrangement of I-ions from dispersive to aggregative and the variation of Br-vacancy and interstitial density.<sup>24,42,54,61</sup> As a result, the  $\tau_{\text{Br}}^1$  can be assigned to excitonic recombination from net  $\text{CsPbBr}_3$  lattice. The decrease of  $\tau_{\text{Br}}^1$  at

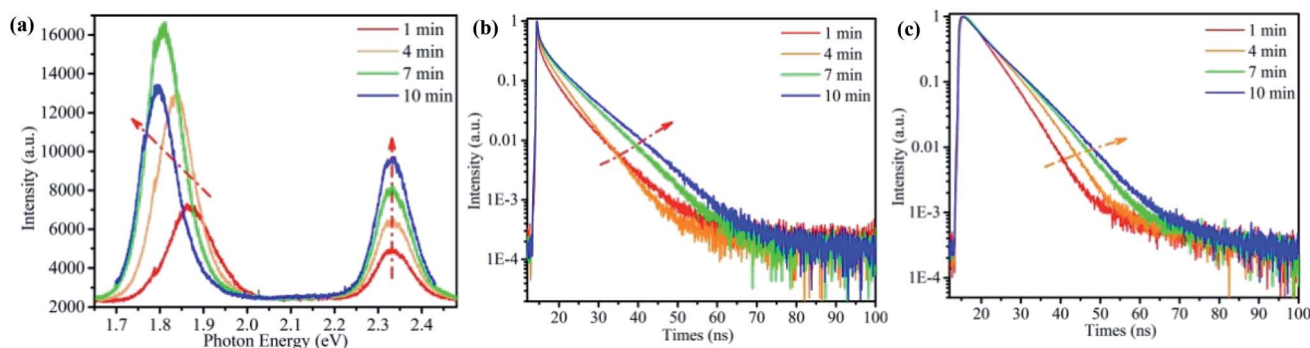


Fig. 4 (a) Evolution of PL spectra with irradiation time for a single  $\text{CsPbBr}_x\text{I}_{3-x}$  microsheet under pulse laser ( $\lambda = 375$  nm, 10 MHz repetition rate,  $\sim 200$  pJ per pulse). (b and c) The corresponding PL decays of Br-rich peak and I-rich peak under different irradiation time.



the first stage is due to the increasing density of vacancy induced by ion migration. Then benefitting from restoration of CsPbBr<sub>3</sub> crystal lattice by laser,  $\tau_{\text{Br}}^1$  would increase.<sup>36,61</sup>  $\tau_{\text{Br}}^2$  could be assigned to impurity ( $\Gamma^-$ ) or defects induced non-radiative recombination.<sup>36,61</sup> Its amplitude decreased due to aggregation of  $\Gamma^-$ . At the same time,  $\tau_1^1$  and  $\tau_1^2$  lengthen with the enhancement of I-rich phase.<sup>40,59</sup> The third ( $\tau_1^3$ ) has lesser importance but behaves in a bizarre way. It may play the aggregative role of other subordinate and complex mechanisms.

For CsPbBr<sub>x</sub>I<sub>3-x</sub> micro-sheets, the influence induced by iodine ions to temperature dependent PL spectra has not been investigated. Here, we measured the temperature dependent PL spectra from 123 to 273 K with a temperature interval of 25 K (Fig. 5a). According to the reports that light induced phase instability can be suppressed at the temperature lower than 250 K for CsPbBr<sub>x</sub>I<sub>3-x</sub> film and nanowire,<sup>62</sup> we cooled the sample to 123 K firstly to suppress the influence from laser excitation. Lorentz/Gaussian decomposition was used to fit the Br-rich (Fig. S7a†) and I-rich peaks (Fig. S7b†). The peak positions, FWHM and PL intensity *versus* temperature of all the four peaks derived from the peak decomposition were plotted in Fig. 6.

As shown in Fig. 6a and b, the peak positions showed a linear blue-shift *versus* temperature for the two Br-rich peaks and the lower energy I-rich peak ( $\sim 1.779$  eV). The blue shifts of high and low energy Br-rich peaks are 14.38 and 7.27 meV. In contrast, the blue-shift of the lower energy I-rich peak is 34 meV. In the previous reported results, the blue shift in lead trihalide perovskites was attributed to the multi-phonon-assisted step-up process, contrary to the red shift of excitonic emission due to band-gap shrinkage in typical semiconductors. In this process, thermal lattice expansion increases the lattice constant, yielding the increased exciton-phonon coupling, so the carriers can reach a higher energy states by absorption phonon with increasing temperature.<sup>32</sup> According to the multi-phonon-assisted step-up process, the more shift of peak position imply the stronger exciton-phonon coupling when the same phonon energy was employed.

Generally, the dependence of FWHM with temperature for excitonic emission can be expressed by Toyozawa's equation:  $\Gamma(T) = \Gamma_0 + E_{\text{EP}}/[\exp(E_{\text{ph}}/k_{\text{B}}T) - 1]$ , where  $\Gamma(T)$  is FWHM at  $T$  K,

$\Gamma_0$  is the line width at absolute temperature 0 K,  $E_{\text{EP}}$  is the exciton-phonon coupling energy,  $E_{\text{ph}}$  is the longitudinal optical-phonon (LO) energy,  $k_{\text{B}}$  is the Boltzmann constant.<sup>31,32,39,57,63</sup> As shown in Fig. 6c, by using the previously reported  $E_{\text{ph}}$  of 19 meV,<sup>39,56,58</sup> we can fit the experimental data well. For the two Br-rich peaks, the exciton-phonon coupling energy  $E_{\text{EP}}$  were 50 and 32.2 meV, smaller slightly than the previous reported value for CsPbBr<sub>3</sub> QDs ( $\sim 65$  meV),<sup>31,56</sup> indicating the weaker exciton-phonon coupling for the Br-rich peaks in CsPbBr<sub>x</sub>I<sub>3-x</sub> compared to the pure CsPbBr<sub>3</sub>. Meanwhile, the relative exciton-phonon coupling strength could explain the different variation extent of two Br-rich peak positions. In contrast, we found that  $E_{\text{EP}}$  can be up to 60.37 meV for the lower energy I-rich peak when 26 meV was employed for  $E_{\text{ph}}$  (Fig. 6d).<sup>32,39</sup> The FWHM can reflect effectively the exciton-phonon coupling strength in CsPb(Br/I)<sub>3</sub> QDs and MAPbBr<sub>x</sub>I<sub>3-x</sub> flim.<sup>32,64</sup> It is believed that lattice strain induced by the different sizes of Br and I within the mixed-halide perovskites gives rise to shifts in the phonon vibration energies relative to those of simplex halide counterparts.<sup>32,64,65</sup>

The more interesting is that the I-rich peak is composed by many sub-bands, as shown in Fig. 5b. Combination the above discussion with the obvious optical waveguide showing in the inset of Fig. 5b, these sub-bands emission should attribute to the strong exciton-phonon coupling for I-rich peak,<sup>66</sup> similar with our previous report on CsPbBr<sub>3</sub> microwires.<sup>56</sup> This observation also shows a possibility for the application of CsPbBr<sub>x</sub>-I<sub>3-x</sub> micro-sheets in integrated optics or laser.

The temperature-dependent emission intensity  $I(T)$  can be understood using the Arrhenius function (two-step quenching model):  $I(T) = I_0/[1 + A_1 \exp(-E_1/k_{\text{B}}T) + A_2 \exp(-E_2/k_{\text{B}}T)]$ , where  $I_0$  is the PL intensity at 0 K,  $E_1$  and  $E_2$  are the temperature activation energies of non-radiative pathways,  $A_1$  and  $A_2$  are coefficients relation to the strength of the quenching processes.<sup>32,36,58</sup> For the high and low energy Br-rich peaks, a good fit could be done, yielding the exciton binding energy of 86.2 meV and 77.8 meV (Fig. 6e), respectively. They are several times larger than the exciton binding energy of pure CsPbBr<sub>3</sub>.<sup>31,36,39,67</sup> In consideration of the arising of others peaks around the Br-rich peaks with decreasing temperature, it is reasonable to speculate that the non-radiative activation energy

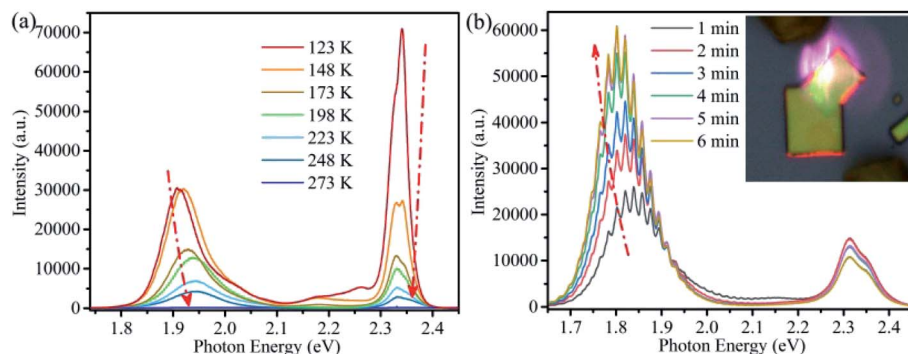


Fig. 5 (a) Temperature dependent PL spectra of a single CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheet. (b) Evolution of PL spectra with irradiation time of another CsPbBr<sub>x</sub>I<sub>3-x</sub> microsheet. Inset is the corresponding emission image, showing evident optical waveguide.



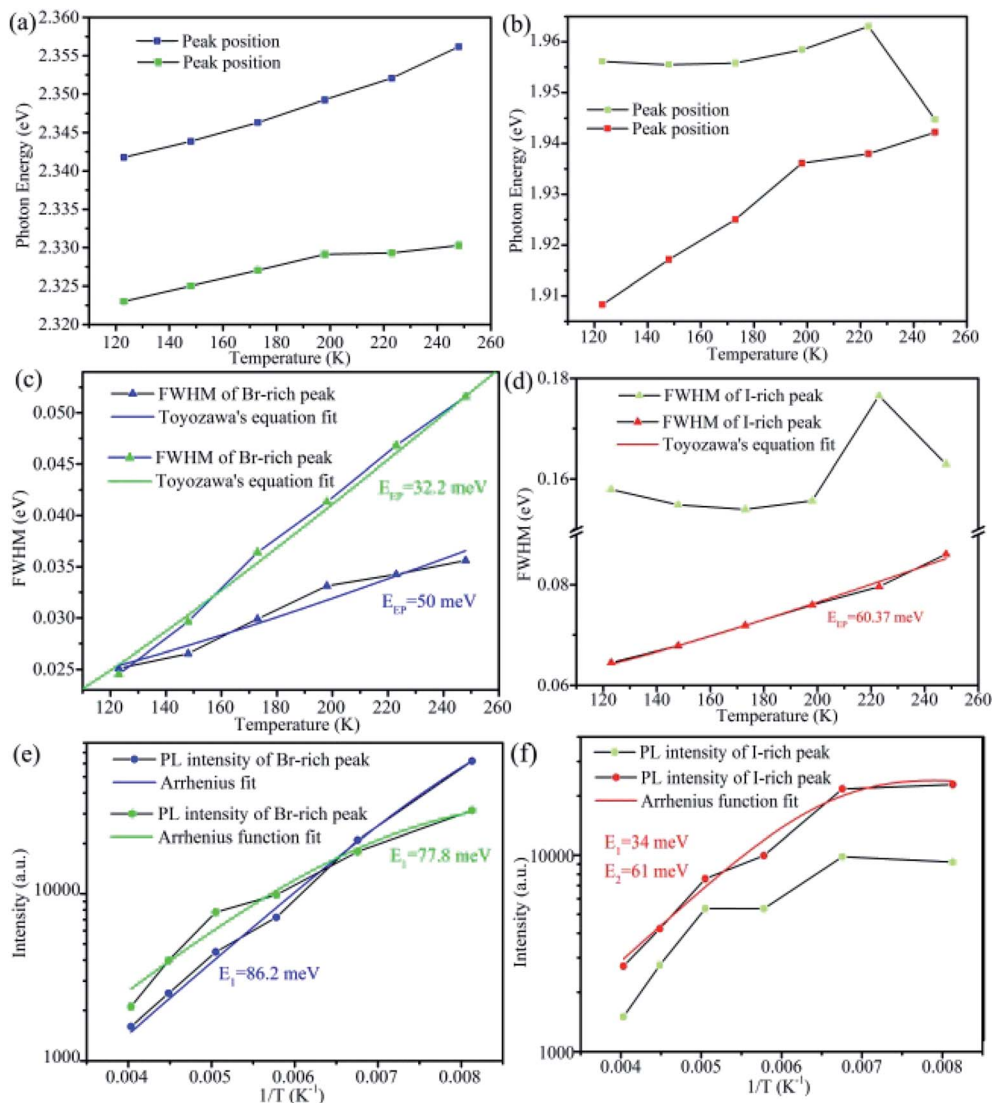


Fig. 6 (a and b) Photon energy of Br-rich and I-rich peaks versus temperature, respectively. (c and d) FWHM of Br-rich and I-rich peaks versus temperature. The solid curves are the fitted curves using Toyozawa's equation. (e and f) PL intensity of Br-rich and I-rich peaks versus temperature.

origins from trap or localized states.<sup>32</sup> It is necessary to note that more irregular patterns are observed for the two I-rich peaks. Especially for the high energy I-rich peak, good fit can't be done to match the experiment results. According to the published papers, phase transition could bring similar anomalous behavior in the mixed halide perovskites.<sup>57,64,68</sup> However, there was no phase transition transformation in the present CsPbBr<sub>3-x</sub>I<sub>x</sub> microsheets, on the basis of the previous reporters.<sup>69-72</sup> We speculated that these irregular patterns might come from their defect-related nature. Further investigation is needed to understand this complex mechanism.

## 4 Conclusions

In conclusion, we grew the high crystallized CsPbBr<sub>3</sub>I<sub>3-x</sub> microsheets by a simple anti-solvent solution method and demonstrated the stable green and red dual-color emission in

a single microsheet. The green and red emissions are attributed to the excitonic and defect related recombination of CsPbBr<sub>3</sub> and CsPbI<sub>3</sub>, respectively. The dual-colors emission is impacted by laser induced phase segregation and defect healing effects, exhibiting a shifting peak, decreasing FWHM along with lengthening lifetime under laser irradiation. The peak positions and FWHM extracted from the temperature-dependent PL suggested the distinctive exciton-phonon coupling of Br-rich and I-rich peaks. This work provides a new pathway to produce stable dual-colors emission to find potential application in integrated optics system.

## 5 Notes

The manuscript was written through contributions of all authors. All authors have given approval to the final version of the manuscript.



## Conflicts of interest

The authors declare no competing financial interest.

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